# PDTC124X series

NPN resistor-equipped transistors; R1 = 22 k $\Omega$ , R2 = 47 k $\Omega$ Rev. 07 — 16 November 2009 Product data sl

Product data sheet

# 1. Product profile

# 1.1 General description

NPN Resistor-Equipped Transistors (RET) family.

Table 1. **Product overview** 

Type number	Package			PNP complement	
	NXP	JEITA	JEDEC		
PDTC124XE	SOT416	SC-75	-	PDTA124XE	
PDTC124XEF	SOT490	SC-89	-	PDTA124XEF	
PDTC124XK	SOT346	SC-59A	TO-236	PDTA124XK	
PDTC124XM	SOT883	SC-101	-	PDTA124XM	
PDTC124XS[1]	SOT54	SC-43A	TO-92	PDTA124XS	
PDTC124XT	SOT23	-	TO-236AB	PDTA124XT	
PDTC124XU	SOT323	SC-70	-	PDTA124XU	

<sup>[1]</sup> Also available in SOT54A and SOT54 variant packages (see Section 2).

### 1.2 Features

- Built-in bias resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs

# 1.3 Applications

- General-purpose switching and amplification
- Inverter and interface circuits

#### Circuit drivers

## 1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{CEO}$	collector-emitter voltage	open base	-	-	50	V
Io	output current		-	-	100	mA
R1	bias resistor 1 (input)		15.4	22	28.6	$k\Omega$
R2/R1	bias resistor ratio		1.7	2.1	2.6	



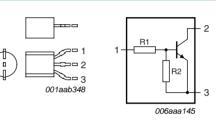
# 2. Pinning information

Table 3. Pinning

Pin	Description	Simplified outline Symbol
SOT54		
1	input (base)	
2	output (collector)	
3	GND (emitter)	001aab347 1 R1 R2

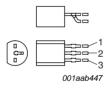
90	т	51	Λ
30	1.5	74	М

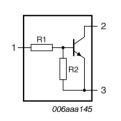
1	input (base)
2	output (collector)
3	GND (emitter)



#### **SOT54** variant

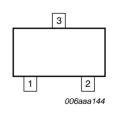
1	input (base)
2	output (collector)
3	GND (emitter)

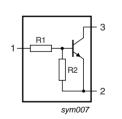




## SOT23; SOT323; SOT346; SOT416; SOT490

1	input (base)
2	GND (emitter)
3	output (collector)

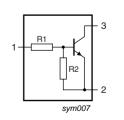




## **SOT883**

1	input (base)
2	GND (emitter)
3	output (collector)





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NPN resistor-equipped transistors; R1 = 22 k $\Omega$ , R2 = 47 k $\Omega$ 

#### **Ordering information** 3.

Table 4. **Ordering information** 

Type number	Package					
	Name	Description	Version			
PDTC124XE	SC-75	plastic surface mounted package; 3 leads	SOT416			
PDTC124XEF	SC-89	plastic surface mounted package; 3 leads	SOT490			
PDTC124XK	SC-59A	plastic surface mounted package; 3 leads	SOT346			
PDTC124XM	SC-101	leadless ultra small plastic package; 3 solder lands; body 1.0 $\times$ 0.6 $\times$ 0.5 mm	SOT883			
PDTC124XS <sup>[1]</sup>	SC-43A	plastic single-ended leaded (through hole) package; 3 leads	SOT54			
PDTC124XT	-	plastic surface mounted package; 3 leads	SOT23			
PDTC124XU	SC-70	plastic surface mounted package; 3 leads	SOT323			

<sup>[1]</sup> Also available in SOT54A and SOT54 variant packages (see Section 2 and Section 9).

#### **Marking** 4.

**Product data sheet** 

Table 5. **Marking codes** 

Type number	Marking code <sup>[1]</sup>
PDTC124XE	32
PDTC124XEF	32
PDTC124XK	51
PDTC124XM	DZ
PDTC124XS	TC124X
PDTC124XT	*46
PDTC124XU	*51

<sup>[1] \* = -:</sup> made in Hong Kong

<sup>\* =</sup> p: made in Hong Kong

<sup>\* =</sup> t: made in Malaysia

<sup>\* =</sup> W: made in China

# 5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
$V_{CBO}$	collector-base voltage	open emitter		-	50	V
$V_{CEO}$	collector-emitter voltage	open base		-	50	V
$V_{EBO}$	emitter-base voltage	open collector		-	7	V
VI	input voltage					
	positive			-	+40	V
	negative			-	<b>-7</b>	V
Io	output current			-	100	mA
I <sub>CM</sub>	peak collector current	single pulse; $t_p \le 1 \text{ ms}$		-	100	mA
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25  ^{\circ}C$				
	SOT416		<u>[1]</u>	-	150	mW
	SOT490		[1][2]	-	250	mW
	SOT346		<u>[1]</u>	-	250	mW
	SOT883		[2][3]	-	250	mW
	SOT54		<u>[1]</u>	-	500	mW
	SOT23		<u>[1]</u>	-	250	mW
	SOT323		<u>[1]</u>	-	200	mW
T <sub>stg</sub>	storage temperature			-65	+150	°C
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-65	+150	°C

<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

<sup>[2]</sup> Reflow soldering is the only recommended soldering method.

<sup>[3]</sup> Device mounted on an FR4 PCB with 60  $\mu m$  copper strip line, standard footprint.

# 6. Thermal characteristics

Table 7. Thermal characteristics

Symbol	Parameter	Conditions	N	lin T	ур Мах	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air				
	SOT416		<u>[1]</u> -	-	833	K/W
	SOT490		[1][2]	-	500	K/W
	SOT346		<u>[1]</u> -	-	500	K/W
	SOT883		[2][3]	-	500	K/W
	SOT54		<u>[1]</u> -	-	250	K/W
	SOT23		<u>[1]</u> -	-	500	K/W
	SOT323		<u>[1]</u> _	-	625	K/W

<sup>[1]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

# 7. Characteristics

Table 8. Characteristics

 $T_{amb} = 25 \, ^{\circ}\text{C}$  unless otherwise specified.

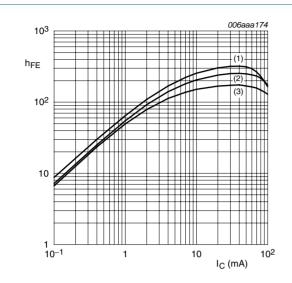
G						
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$I_{CBO}$	collector-base cut-off current	$V_{CB} = 50 \text{ V}; I_E = 0 \text{ A}$	-	-	100	nA
I <sub>CEO</sub>	collector-emitter cut-off current	$V_{CE} = 30 \text{ V}; I_{B} = 0 \text{ A}$	-	-	1	μΑ
		$V_{CE} = 30 \text{ V}; I_{B} = 0 \text{ A};$ $T_{j} = 150 ^{\circ}\text{C}$	-	-	50	μΑ
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; I_C = 0 \text{ A}$	-	-	120	μΑ
h <sub>FE</sub>	DC current gain	$V_{CE} = 5 \text{ V}; I_{C} = 5 \text{ mA}$	80	-	-	
$V_{CEsat}$	collector-emitter saturation voltage	$I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}$	-	-	150	mV
$V_{I(off)}$	off-state input voltage	$V_{CE} = 5 \text{ V}; I_{C} = 100 \mu\text{A}$	-	8.0	0.5	V
V <sub>I(on)</sub>	on-state input voltage	$V_{CE}$ = 300 mV; $I_{C}$ = 2 mA	2	1.1	-	V
R1	bias resistor 1 (input)		15.4	22	28.6	$k\Omega$
R2/R1	bias resistor ratio		1.7	2.1	2.6	
C <sub>c</sub>	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = i_e = 0 \text{ A};$ f = 1 MHz	-	-	2.5	pF

<sup>[2]</sup> Reflow soldering is the only recommended soldering method.

<sup>[3]</sup> Device mounted on an FR4 PCB with 60  $\mu m$  copper strip line, standard footprint.

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NPN resistor-equipped transistors; R1 = 22 k $\Omega$ , R2 = 47 k $\Omega$ 

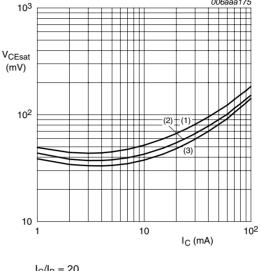


$$V_{CE} = 5 V$$

(1) 
$$T_{amb} = 100 \, ^{\circ}C$$

(3) 
$$T_{amb} = -40 \, ^{\circ}C$$

Fig 1. DC current gain as a function of collector current; typical values



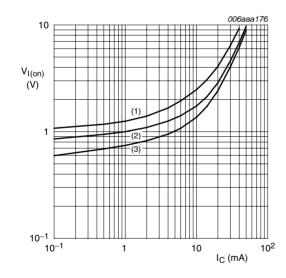
$$I_{\rm C}/I_{\rm B} = 20$$

(1) 
$$T_{amb} = 100 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = -40 \, ^{\circ}C$$

Fig 2. Collector-emitter saturation voltage as a function of collector current; typical values



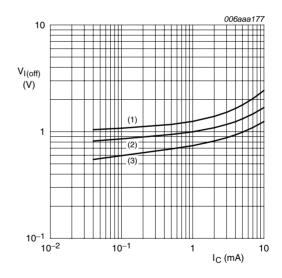
$$V_{CE} = 0.3 \text{ V}$$

(1) 
$$T_{amb} = -40 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = 100 \, ^{\circ}C$$

Fig 3. On-state input voltage as a function of collector current; typical values



$$V_{CE} = 5 V$$

(1) 
$$T_{amb} = -40 \, ^{\circ}C$$

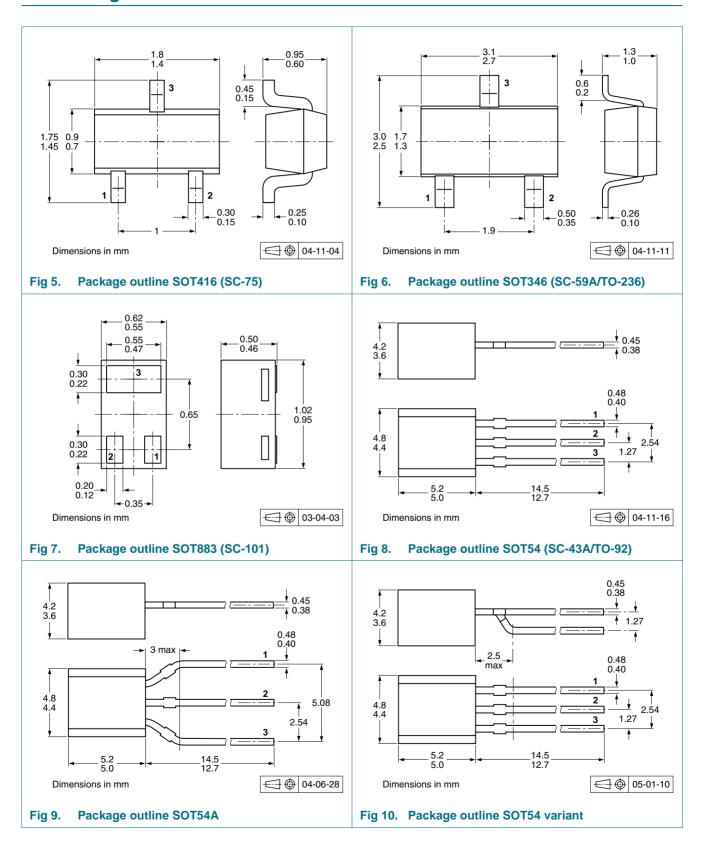
(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = 100 \, ^{\circ}C$$

Fig 4. Off-state input voltage as a function of collector current; typical values

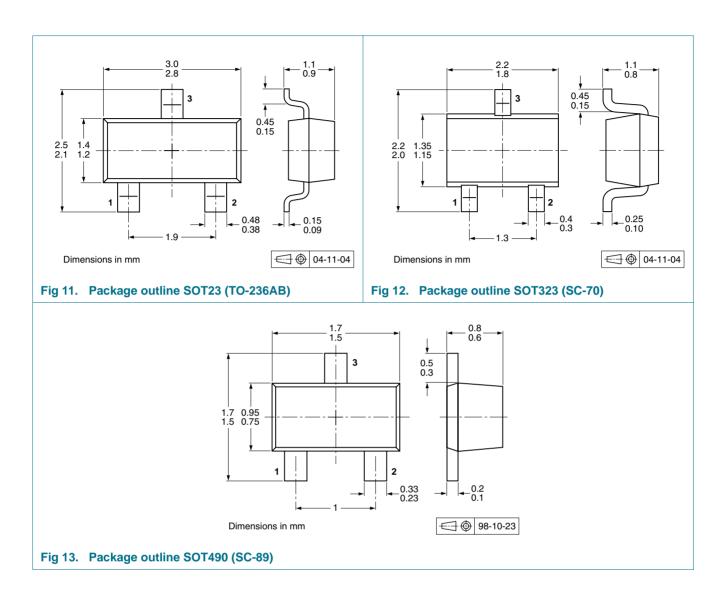
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# 8. Package outline



# PDTC124X series

NPN resistor-equipped transistors; R1 = 22 k $\Omega$ , R2 = 47 k $\Omega$ 



**Product data sheet** 

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NPN resistor-equipped transistors;  $R1 = 22 \text{ k}\Omega$ ,  $R2 = 47 \text{ k}\Omega$ 

#### **Packing information** 9.

Table 9. **Packing methods** 

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing quantity			
			3000	4000	5000	10000
PDTC124XE	SOT416	4 mm pitch, 8 mm tape and reel	-115	-	-	-135
PDTC124XEF	SOT490	4 mm pitch, 8 mm tape and reel	-	-115	-	-
PDTC124XK	SOT346	4 mm pitch, 8 mm tape and reel	-115	-	-	-135
PDTC124XM	SOT883	2 mm pitch, 8 mm tape and reel	-	-	-	-315
PDTC124XS	SOT54	bulk, straight leads	-	-	-412	-
	SOT54A	tape and reel, wide pitch	-	-	-	-116
		tape ammopack, wide pitch	-	-	-	-126
	SOT54 variant	bulk, delta pinning	-	-	-112	-
PDTC124XT	SOT23	4 mm pitch, 8 mm tape and reel	-215	-	-	-235
PDTC124XU	SOT323	4 mm pitch, 8 mm tape and reel	-115	-	-	-135

<sup>[1]</sup> For further information and the availability of packing methods, see Section 12.



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NPN resistor-equipped transistors; R1 = 22 k $\Omega$ , R2 = 47 k $\Omega$ 

# 10. Revision history

## Table 10. Revision history

**Product data sheet** 

Document ID	Release date	Data sheet status	Change notice	Supersedes
PDTC124X_SER_7	20091116	Product data sheet	-	PDTC124X_SER_6
Modifications:		et was changed to reflect the legal definitions and disclair		
PDTC124X_SER_6	20050714	Product data sheet	-	PDTC124X_SERIES_5
PDTC124X_SERIES_5	20040813	Product specification	-	PDTC124X_SERIES_4
PDTC124X_SERIES_4	20030410	Product specification	-	PDTC124XEF_2 PDTC124XE_3
PDTC124XE_3	19990518	Product specification	-	PDTC124XE_2
PDTC124XE_2	19980921	Product specification	-	PDTC124XE_1
PDTC124XE_1	19971215	Product specification	-	-
PDTC124XEF_2	19990518	Preliminary specification	-	PDTC124XEF_1
PDTC124XEF_1	19981111	Preliminary specification	-	-

# 11. Legal information

#### 11.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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# PDTC124X series

# NPN resistor-equipped transistors; $R1 = 22 \text{ k}\Omega$ , $R2 = 47 \text{ k}\Omega$

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